

DMTH4007SPSQ

40V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

### **Product Summary**

BV <sub>DSS</sub>	Rds(on) Max	I <sub>D</sub> Max Tc = +25°C (Note 9)
40V	7.6mΩ @ Vgs = 10V	100A

## **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Power managements
- DC-DC converters
- Motor controls

Site 1:

Features

- Rated to +175°C Ideal for High Ambient Temperature Environments
- Thermally Efficient Package Cooler Running Applications
- High Conversion Efficiency
- Low R<sub>DS(ON)</sub> Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- <1.1mm Package Profile Ideal for Thin Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH4007SPSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (@3)

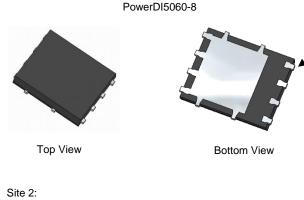
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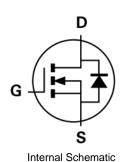
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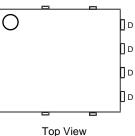
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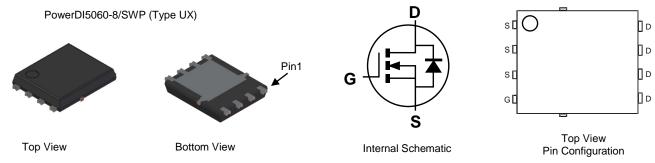
Weight: 0.097 grams (Approximate)







Pin Configuration



Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

Pin1

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

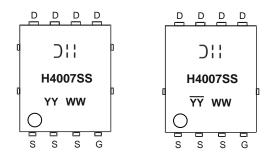


### Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackage	Qty.	Carrier	
DMTH4007SPSQ-13	PowerDI5060-8	2,500	Tape & Reel	
DMTH4007SPSQ-13	PowerDI5060-8/SWP (Type UX)	2,500	Tape & Reel	

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



**D¦ !** = Manufacturer's Code Marking H4007SS = Product Type Marking Code YYWW = Date Code Marking YY or  $\overline{YY}$  = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)

### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		Vdss	40	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current (Note 5)	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	15.7 13.1	A
Continuous Drain Current (Note 6)	T <sub>C</sub> = +25°C (Note 9) T <sub>C</sub> = +100°C	ID	100 77	A
Maximum Continuous Body Diode Forward Current	t (Note 6)	ls	100	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		IDM	120	А
Avalanche Current, L = 0.3mH		I <sub>AS</sub>	20	A
Avalanche Energy, L = 0.3mH		Eas	60	mJ

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T <sub>A</sub> = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)		Reja	53	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	136	W
Thermal Resistance, Junction to Case (Note 6)		R <sub>θJC</sub>	1.1	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

6. Thermal resistance from junction to soldering point (on the exposed drain pad).

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

9. Package limited.



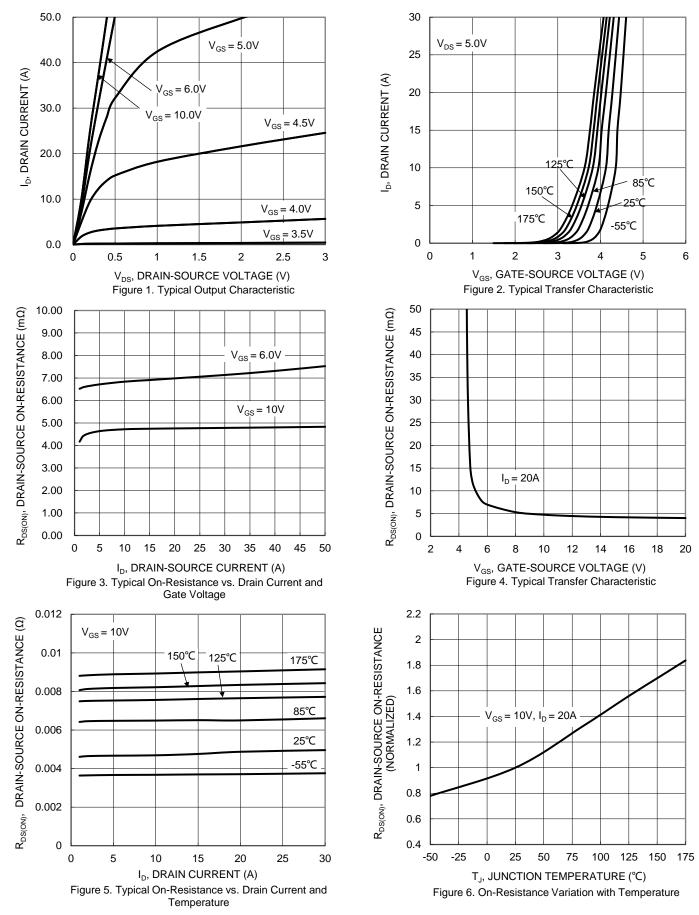
# Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Мах	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)		Oymbol		TYP	Max	Onit	rest condition	
Drain-Source Breakdown Voltage		BVDSS	40	_	_	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	
		IDSS		—	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current	(Note 8)	IDSS	_	_	100	μA	V <sub>DS</sub> = 32V, V <sub>GS</sub> = 0V, T <sub>J</sub> = +125°C	
Gate-Source Leakage	•	lgss		—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)								
Gate Threshold Voltage		Vgs(th)	2	_	4	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		RDS(ON)		4.9	7.6	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 20A	
Diode Forward Voltage		V <sub>SD</sub>		_	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 8)								
Input Capacitance		Ciss	_	2,082	—			
Output Capacitance		Coss		790	—	pF	Vps = 25V, Vgs = 0V, f = 1MHz	
Reverse Transfer Capacitance		Crss		113	-			
Gate Resistance		Rg	0.1	0.46	1.4	Ω	$V_{DS} = 0V$ , $V_{GS} = 0V$ , $f = 1MHz$	
Total Gate Charge		Qg	_	41.9	—			
Gate-Source Charge		Qgs	_	10	—	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 20A, V <sub>GS</sub> = 10V	
Gate-Drain Charge		Qgd	_	11.5	—			
Turn-On Delay Time		td(on)	_	7	—			
Turn-On Rise Time		t <sub>R</sub>	_	11.5	—		$V_{DD} = 30V, V_{GS} = 10V,$	
Turn-Off Delay Time		tD(OFF)	_	15.6	—	ns	$I_D = 20A, R_G = 3\Omega$	
Turn-Off Fall Time		tF		8.8	—			
Body Diode Reverse Recovery Time		t <sub>RR</sub>		29.9	—	ns		
Body Diode Reverse Recovery Charge		Qrr	_	23	—	nC	IF = 20A, di/dt = 100A/μs	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

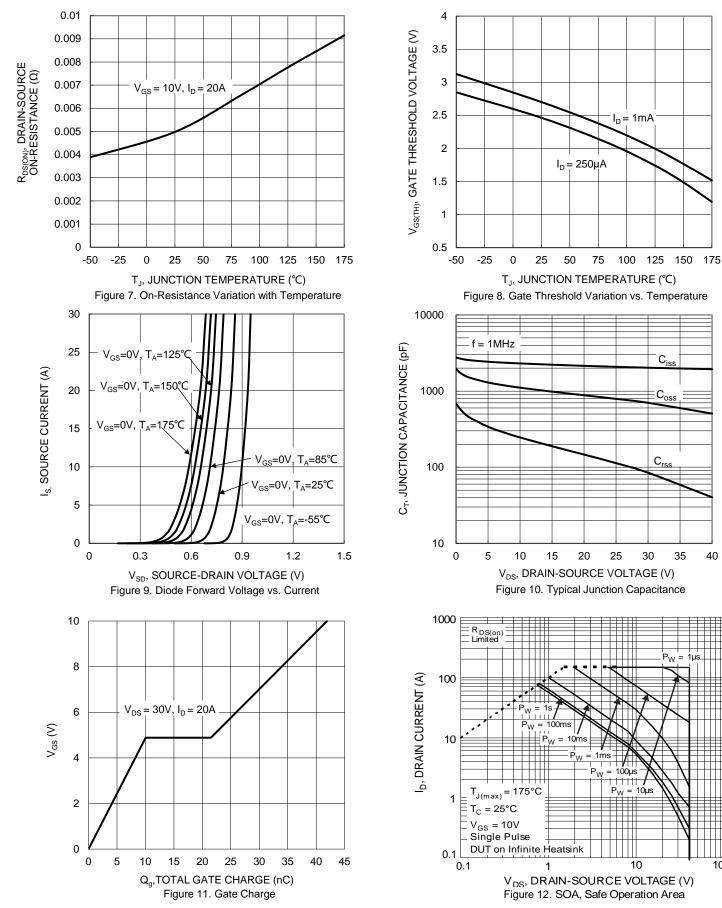


## DMTH4007SPSQ





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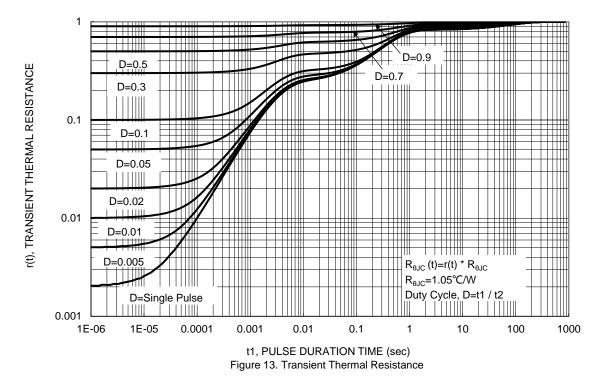
DMTH4007SPSQ Document number: DS38160 Rev. 2 - 2

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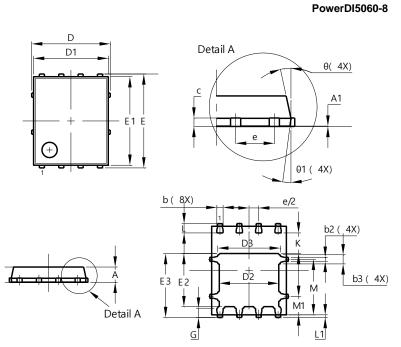




## **Package Outline Dimensions**

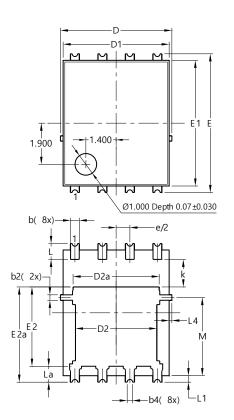
Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

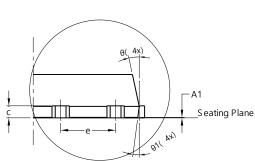


	PowerDI5060-8					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
E		6.15 BSC	;			
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е		1.27 BSC				
G	0.51	0.71	0.61			
К	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
01	6°	8°	7°			
Al	Dimens	ions in n	1m			

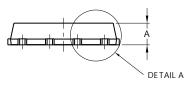
Site 2:



#### PowerDI5060-8/SWP (Type UX)



DETAIL A



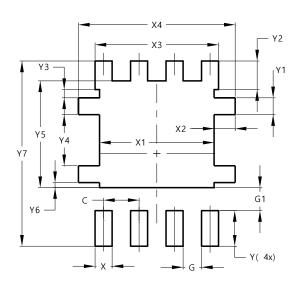
PowerDI5060-8/SWP (Type UX)				
Dim	Min	Max	Тур	
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	C	).25REF		
С	0.230	0.330	0.277	
D	5	.15 BS0	0	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
E	6	.40 BS0	0	
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	.27BSC	)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	0.050REF			
L4	0.025	0.225	0.125	
М	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	Dimensi	ons in	mm	



# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version. Site 1:

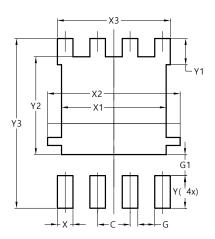
#### PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610

Site 2:

#### PowerDI5060-8/SWP (Type UX)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	5.190
X3	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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